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Team Nexperia

# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

Rev. 11 — 9 December 2011

**Product data sheet** 

### 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTC143XE	SOT416	SC-75	-	PDTA143XE	ultra small
PDTC143XM	SOT883	SC-101	-	PDTA143XM	leadless ultra small
PDTC143XT	SOT23	-	TO-236AB	PDTA143XT	small
PDTC143XU	SOT323	SC-70	-	PDTA143XU	very small

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	



## 2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

## 3. Ordering information

Table 4. Ordering information

PDTC143XE	Name	Description	1
PDTC143XE		Description	Version
	SC-75	plastic surface-mounted package; 3 leads	SOT416
PDTC143XM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883
PDTC143XT	-	plastic surface-mounted package; 3 leads	SOT23
PDTC143XU	SC-70	plastic surface-mounted package; 3 leads	SOT323

## 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTC143XE	34
PDTC143XM	E2
PDTC143XT	*32
PDTC143XU	*53

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

Table 6. Limiting values

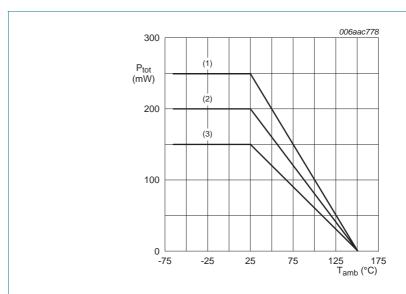
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	7	V
VI	input voltage				
	positive		-	+20	V
	negative		-	<b>-7</b>	V
I <sub>O</sub>	output current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PDTC143XE (SOT416)		[1][2] _	150	mW
	PDTC143XM (SOT883)		[2][3]	250	mW
	PDTC143XT (SOT23)		[1] -	250	mW
	PDTC143XU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70  $\mu m$  copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

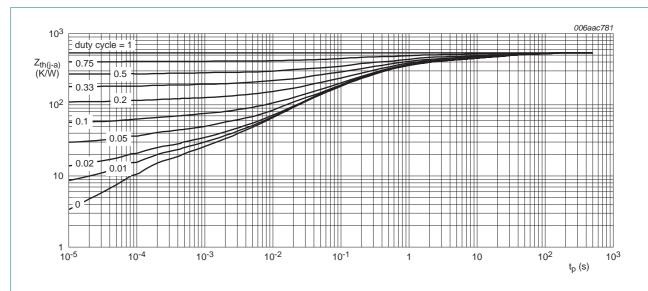
Fig 1. Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

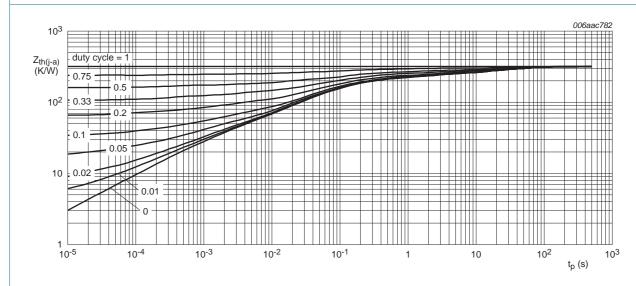
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTC143XE (SOT416)		[1][2]	-	830	K/W
	PDTC143XM (SOT883)		[2][3]	-	500	K/W
	PDTC143XT (SOT23)		[1] -	-	500	K/W
	PDTC143XU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XE (SOT416); typical values



FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XM (SOT883); typical values

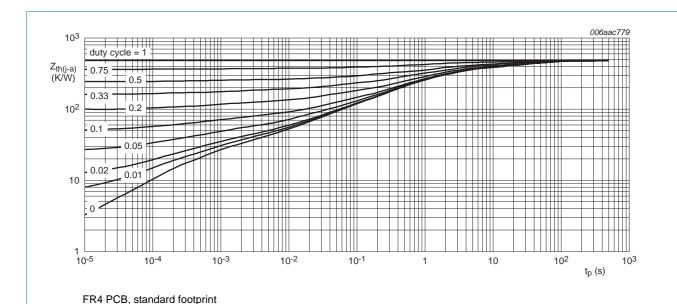


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XT (SOT23); typical values

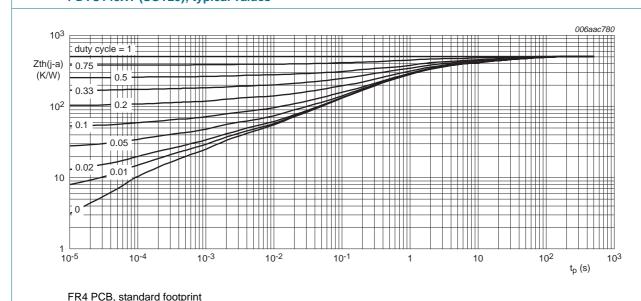


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XU (SOT323); typical values

NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

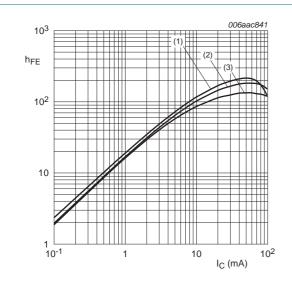
### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
	cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	600	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	50	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-	0.9	0.3	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}$	2.5	1.5	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz	<u>[1]</u> -	230	-	MHz

<sup>[1]</sup> Characteristics of built-in transistor



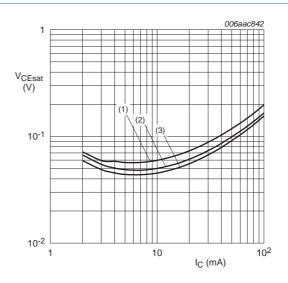
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 6. DC current gain as a function of collector current; typical values



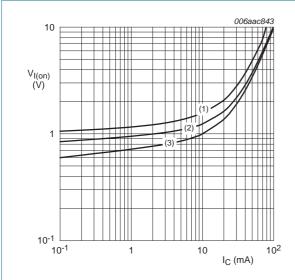
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



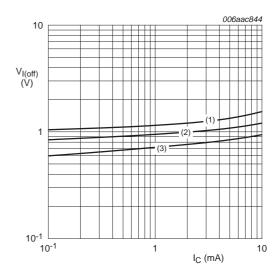
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 9. Off-state input voltage as a function of collector current; typical values

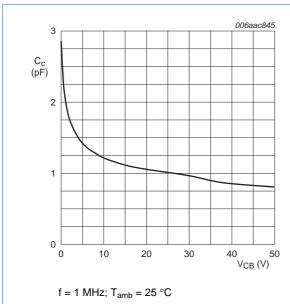


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

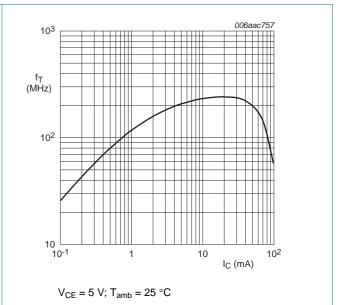


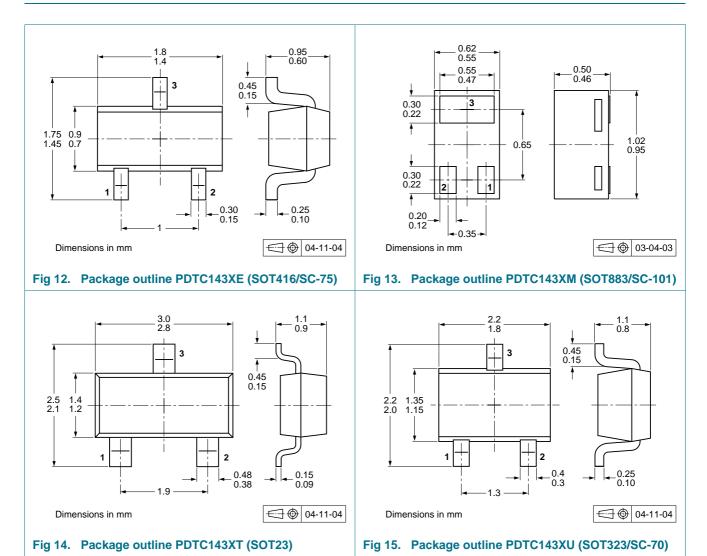
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## 10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	king quantity	
			3000	5000	10000
PDTC143XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC143XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC143XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC143XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

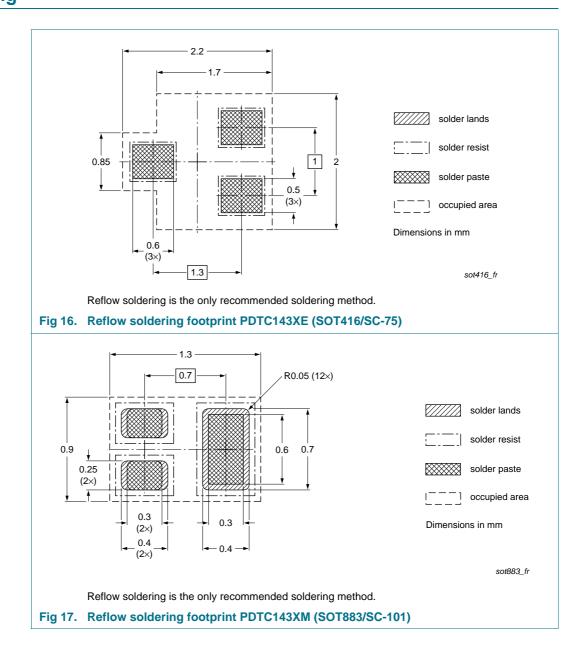
[1] For further information and the availability of packing methods, see Section 14.

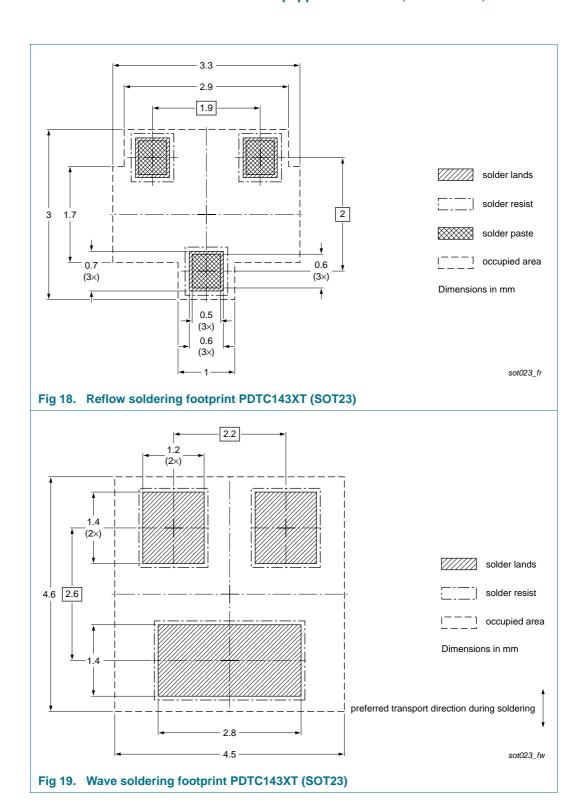
PDTC143X\_SER

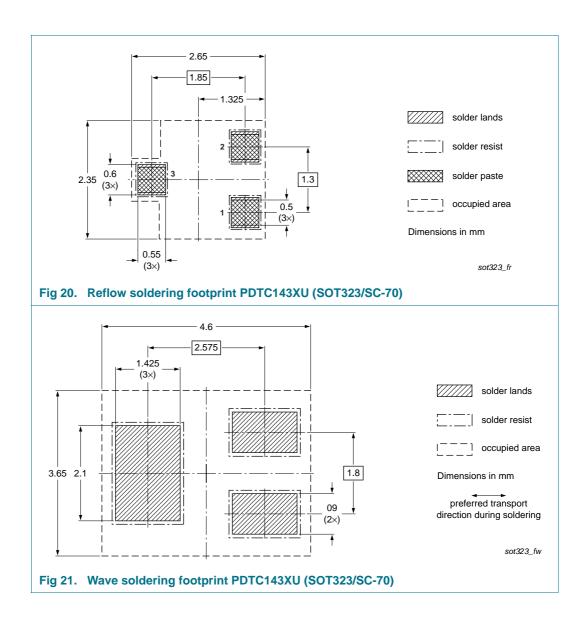
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### 11. Soldering







NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

## 12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC143X_SER v.11	20111209	Product data sheet	-	PDTC143X_SERIES v.10
Modifications:	<ul> <li>Type number</li> <li>Section 1 "Production 2" Pin</li> <li>Section 2 "Pin</li> <li>Section 4 "Ma</li> <li>Figure 1 to 5,</li> <li>Section 6 "Th</li> <li>Figure 6 to 9:</li> <li>Table 8 "Char</li> <li>Section 8 "Te</li> </ul>	s PDTC143XEF, PDTC143X oduct profile": updated nning information": updated arking": updated 10 and 11: added ermal characteristics": upda	ted	emoved.
		egal information": updated		
PDTC143X_SERIES v.10	20091116	Product data sheet	-	PDTC143X_SERIES v.9
PDTC143X_SERIES v.9	20050726	Product data sheet	-	PDTC143X_SERIES v.8
PDTC143X_SERIES v.8	20040806	Product specification	-	PDTC143X_SERIES v.7
PDTC143X_SERIES v.7	20040323	Product specification	-	PDTC143X_SERIES v.6
PDTC143X_SERIES v.6	20040112	Product specification	-	PDTC143X_SERIES v.5
PDTC143X_SERIES v.5	20031112	Product specification	-	PDTC143X_SERIES v.4
PDTC143X_SERIES v.4	20030910	Product specification	-	PDTC143X_SERIES v.3
PDTC143X_SERIES v.3	20030410	Product specification	•	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTC143X\_SER

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# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

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# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

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